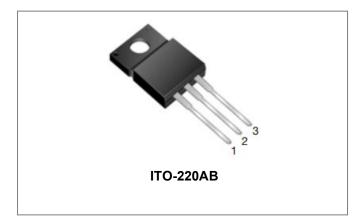


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Technical Data Data Sheet N1325, Rev. A



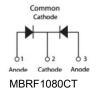
MBRF1080CT (CTR) SCHOTTKY RECTIFIER

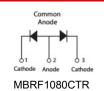


Features

- 150°C T_J operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Terminals finish: Tin Lead-free plated
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram





Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Maximum Ratings(Tc =25°C unless otherwise specified)

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	80	V
Average Rectified Forward Current	I _{F (AV)}	Tc=130°C, In DC	5(Per Leg) 10(Per Device)	A
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I _{FSM}	8.3ms, Half Sine pulse	120	А

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Data Sheet N1325, Rev. A

Electrical Characteristics:



Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop(Per Leg)*	V _{F1}	@ 5A, Pulse, T _J = 25 °C	0.69	0.85	V
		@ 10A, Pulse, TJ = 25 °C	0.87	0.95	v
	VF2	@ 5A, Pulse, T _J = 125 °C	0.60	0.75	V
		@ 10A, Pulse, T」 = 125 °C	0.70	0.85	v
Reverse Current(Per Leg)*	I _{R1}	$@V_R = rated V_{R,} T_J = 25 \ ^{\circ}C$	0.01	1.0	mA
	I _{R2}	@V _R = rated V _R , T _J = 125 °C	7	15	mA
Junction Capacitance(Per Leg)	Ст	@V _R = 5V, T _C = 25 °C, f _{SIG} = 1MHz	187	300	pF
Series Inductance(Per Leg)	Ls	Measured lead to lead 5 mm from	8.0	-	nH
		package body	0.0		
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs
RSM Isolation Voltage	V _{ISO}	Clip mounting, the epoxy body away	-	4500	V
(t = 1.0 second, R. H. < =30%,		from the heatsink edge by more than			
T _A = 25 °C)		0.110" along the lead direction.			
,		Clip mounting, the epoxy body is inside	-	3500	
		the heatsink.			
		Screw mounting, the epoxy body is inside	-	1500	
		the heatsink.			

Pulse width < 300 μ s, duty cycle < 2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	R _{θJC}	DC operation	4.5	°C/W
Approximate Weight	wt	-	2	g
Case Style	ITO-220AB			

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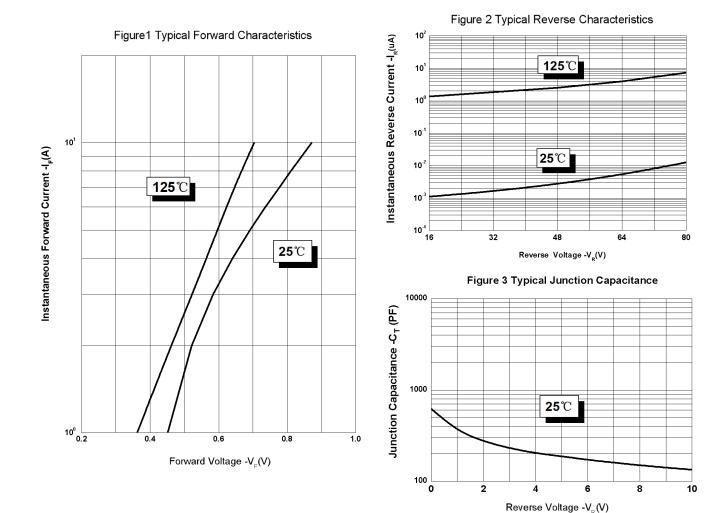


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Technical Data Data Sheet N1325, Rev. A

Ratings and Characteristics Curves

RoHS PO



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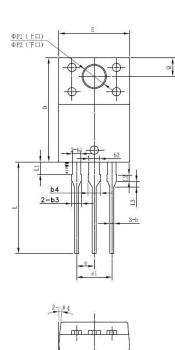
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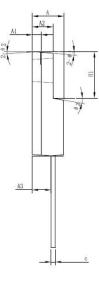
Millimeters

Technical Data Data Sheet N1325, Rev. A



Mechanical Dimensions ITO-220AB

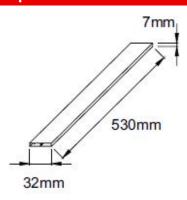




SYMBOL					
STWBOL	MIN.	TYP.	MAX.		
A	4.30	4.50	4.70		
A1	1.10	1.30	1.50		
A2	2.80	3.00	3.20		
A3	2.50	2.70	2.90		
b	0.50	0.60	0.75		
b1	1.10	1.20	1.35		
b2	1.50	1.60	1.75		
b3	1.20	1.30	1.45		
b4	1.60	1.70	1.85		
с	0.50	0.60	0.75		
D	14.80	15.00	15.20		
E	9.96	10.16	10.36		
е		2.55			
e1		5.10			
H1	6.50	6.70	6.90		
L	12.70	13.20	13.70		
L1	1.60	1.80	2.00		
L2	0.80	1.00	1.20		
L3	0.60	0.80	1.00		
ΦΡ1(上口)	3.30	3.50	3.70		
ΦΡ2(下口)	2.99	3.19	3.39		
Q	2.50	2.70	2.90		
Θ1		5°			
Θ2		4°			
Θ3		10°			
Θ4		5°			
Θ5		5°			

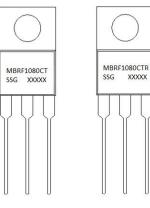
Tube Specification

. 0.5



Marking Diagram

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Where XXXXX is YYWWL

MBR F	= Device Type = Package type
10	= Forward Current (10A)
80	= Reverse Voltage (80V)
CT(CTR)	= Configuration
SSG	= SSG
YY	= Year
WW	= Week
L	= Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

Ordering Information

Device	Package	Shipping
MBRF1080CT(CTR)	ITO-220AB(Pb-Free)	50 pcs/ tube

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Technical Data Data Sheet N1325, Rev. A

MBRF1080CT(CTR)



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